

**DUAL LOW VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS** **AZV358**

**General Description**

The AZV358 is dual low voltage (2.7-5.5V) operational amplifiers which have rail-to-rail output swing capability. The input common-mode voltage range includes ground. The chip exhibits excellent speed-power ratio, achieving 1MHz of bandwidth and 1V/ $\mu$ s of slew rate with low supply current.

The AZV358 is built with BiCMOS process. It has bipolar input and output stages for improved noise performance, low input offset voltage and higher output current drive.

AZV358 is available in the package of TSSOP-8 and MSOP-8. The small packages save space on pc boards, and enable the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

AZV358 is also available in standard SOIC-8 package.

**Features**

(For  $V_{CC}=5V$  and  $V_{EE}=0V$ , typical unless otherwise noted)

- Guaranteed 2.7V to 5.5V Performance
- No Crossover Distortion
- Gain-Bandwidth Product 1MHz
- Industrial Temperature Range: -40°C to +85°C
- Low Supply Current: 210 $\mu$ A
- Rail-to-Rail Output Swing under 10k $\Omega$  Load:  
 $V_{OH}$  up to  $V_{CC} - 10mV$   
 $V_{OL}$  near to  $V_{EE} + 65mV$
- $V_{CM}$ : -0.1V to  $V_{CC} - 0.8V$

**Applications**

- Active Filters
- Low Power, Low Voltage Applications
- General Purpose Portable Devices
- Cellular Phone, Cordless Phone
- Battery-Powered Systems



Figure 1. Package Types of AZV358

**Pin Configuration**

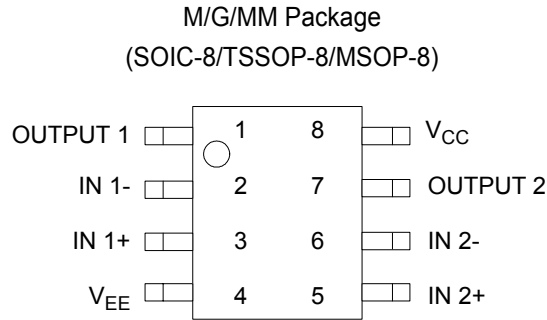


Figure 2. Pin Configuration of AZV358 (Top View)

**Functional Block Diagram**

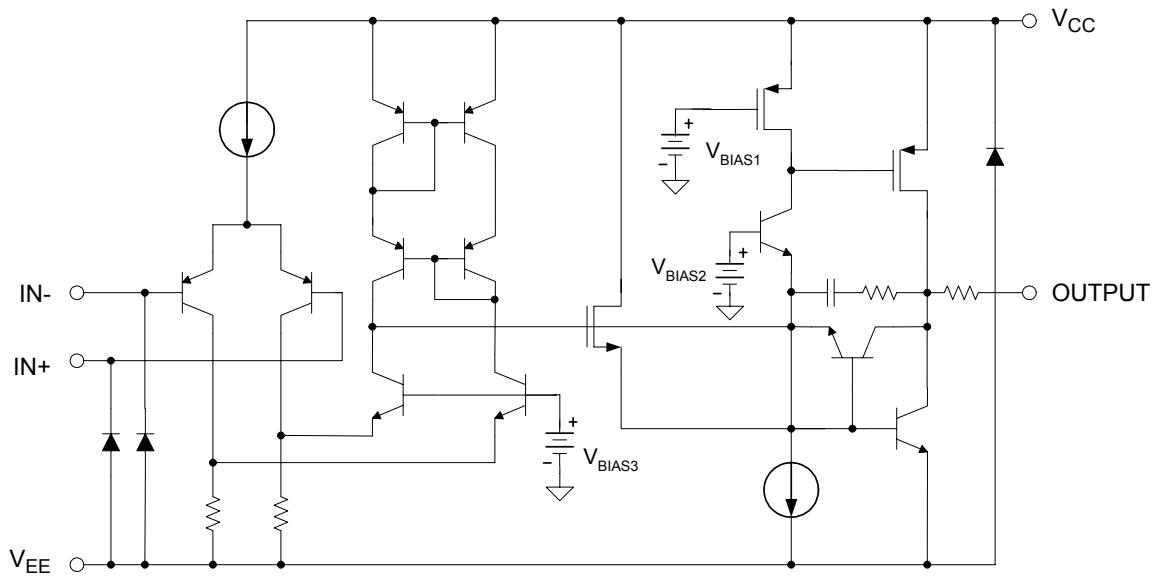
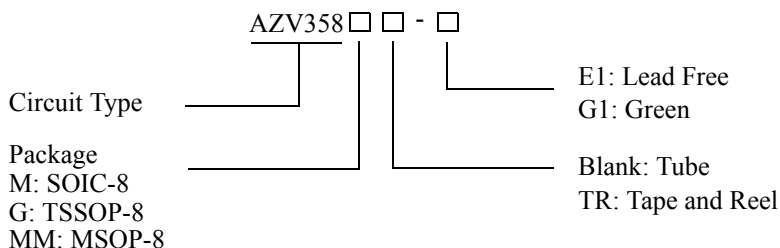


Figure 3. Functional Block Diagram of AZV358 (Each Block)



**DUAL LOW VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS      AZV358**

**Ordering Information**



Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
SOIC-8	-40 to 85°C	AZV358M-E1	AZV358M-G1	AZV358M-E1	AZV358M-G1	Tube
		AZV358MTR-E1	AZV358MTR-G1	AZV358M-E1	AZV358M-G1	Tape & Reel
TSSOP-8	-40 to 85°C	AZV358G-E1	AZV358G-G1	EG3E	GG3E	Tube
		AZV358GTR-E1	AZV358GTR-G1	EG3E	GG3E	Tape & Reel
MSOP-8	-40 to 85°C	AZV358MM-E1	AZV358MM-G1	AZV358MM-E1	AZV358MM-G1	Tube
		AZV358MMTR-E1	AZV358MMTR-G1	AZV358MM-E1	AZV358MM-G1	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Power Supply Voltage	V <sub>CC</sub>	6	V
Operation Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to 150	°C
Lead Temperature (Soldering, 10 Seconds)	T <sub>LEAD</sub>	260	°C
ESD (Machine Model)		200	V
ESD (Human Body Model)		2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

**Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V <sub>CC</sub>	2.7	5.5	V
Ambient Operating Temperature Range	T <sub>A</sub>	-40	85	°C



**DUAL LOW VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS AZV358**

**2.7V Electrical Characteristics**

Limits in standard typeface are for  $T_A=25^{\circ}\text{C}$ , **bold** typeface applies over  $T_A=-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $V_{CC}=2.7\text{V}$ ,  $V_{EE}=0\text{V}$ ,  $V_{CM}=1.0\text{V}$ ,  $V_O=V_{CC}/2$  and  $R_L>1\text{M}\Omega$ , unless otherwise specified. (Note 2)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Offset Voltage	$V_{IO}$			1.7	7	mV
					<b>9</b>	
Input Bias Current	$I_B$			11	250	nA
					<b>500</b>	
Input Offset Current	$I_{IO}$			5	50	nA
					<b>150</b>	
Input Common Mode Voltage Range	$V_{CM}$	for $CMRR \geq 50\text{dB}$	-0.1		1.9	V
Supply Current	$I_{CC}$	$V_O=V_{CC}/2$ , $A_{VCL}=1$ , No load		140	340	$\mu\text{A}$
					<b>420</b>	
Common Mode Rejection Ratio	CMRR	$0 \leq V_{CM} \leq 1.7\text{V}$	50	63		dB
Power Supply Rejection Ratio	PSRR	$2.7\text{V} \leq V_{CC} \leq 5\text{V}$ , $V_O=1\text{V}$ ,	50	60		dB
Output Short Circuit Current	$I_{SOURCE}$	$V_O=0\text{V}$	5	20		mA
	$I_{SINK}$	$V_O=2.7\text{V}$	10	30		mA
Output Voltage Swing	$V_{OH}$	$R_L=10\text{k}\Omega$ to $1.35\text{V}$	2.60	2.69		V
	$V_{OL}$			60	180	mV
Gain Bandwidth Product	GBWP	$C_L=200\text{pF}$		1		MHz
Phase Margin	$\phi_M$			60		deg
Gain Margin	$G_M$			10		dB

Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



**DUAL LOW VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS AZV358**

**5V Electrical Characteristics**

Limits in standard typeface are for  $T_A=25^{\circ}\text{C}$ , **bold** typeface applies over  $T_A=-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $V_{CC}=5\text{V}$ ,  $V_{EE}=0\text{V}$ ,  $V_{CM}=2.0\text{V}$ ,  $V_O=V_{CC}/2$  and  $R_L>1\text{M}\Omega$ , unless otherwise specified. (Note 2)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Offset Voltage	$V_{IO}$			1.7	7	mV
					<b>9</b>	
Input Bias Current	$I_B$			15	250	nA
					<b>500</b>	
Input Offset Current	$I_{IO}$			5	50	nA
					<b>150</b>	
Input Common Mode Voltage Range	$V_{CM}$	for $\text{CMRR}\geq 50\text{dB}$	-0.1		4.2	V
Supply Current	$I_{CC}$	$V_O=V_{CC}/2$ , $A_{VCL}=1$ , No load		210	440	$\mu\text{A}$
					<b>615</b>	
Large Signal Voltage Gain	$G_V$	$R_L=2\text{k}\Omega$	84	100		dB
			<b>80</b>			
Common Mode Rejection Ratio	CMRR	$0\leq V_{CM}\leq 4\text{V}$	50	63		dB
Power Supply Rejection Ratio	PSRR	$2.7\text{V}\leq V_{CC}\leq 5\text{V}$ $V_O=1\text{V}$ , $V_{CM}=1\text{V}$	50	60		dB
Output Short Circuit Current	$I_{SOURCE}$	$V_O=0\text{V}$	5	60		mA
	$I_{SINK}$	$V_O=5\text{V}$	10	160		mA
Output Voltage Swing	$V_{OH}$	$R_L=2\text{k}\Omega$ to 2.5V	4.7	4.96		V
			<b>4.6</b>			
		$R_L=10\text{k}\Omega$ to 2.5V	4.9	4.99		
			<b>4.8</b>			
	$V_{OL}$	$R_L=2\text{k}\Omega$ to 2.5V		120	300	mV
					<b>400</b>	
$R_L=10\text{k}\Omega$ to 2.5V			65	180		
				<b>280</b>		
Slew Rate	SR		1		V/ $\mu\text{s}$	
Gain Bandwidth Product	GBWP	$C_L=200\text{pF}$		1		MHz
Phase Margin	$\phi_M$			60		deg
Gain Margin	$G_M$			10		dB

Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



**Typical Performance Characteristics**

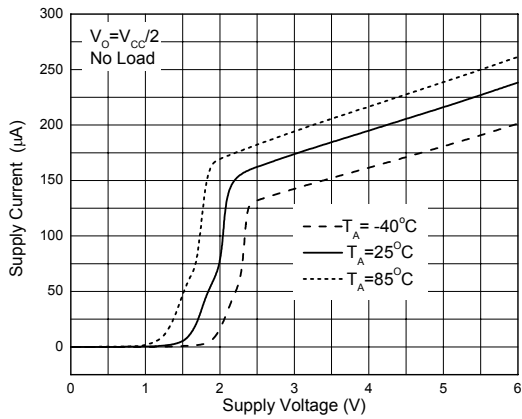


Figure 4. Supply Current vs. Supply Voltage

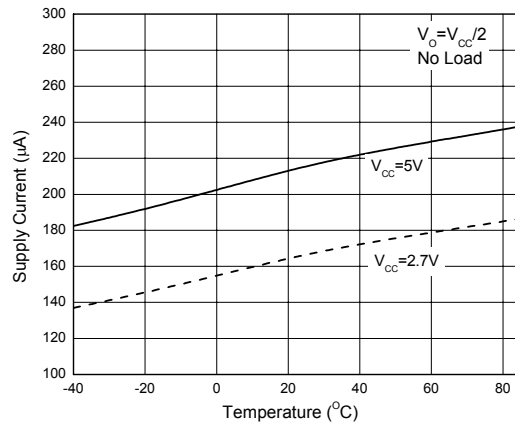


Figure 5. Supply Current vs. Temperature

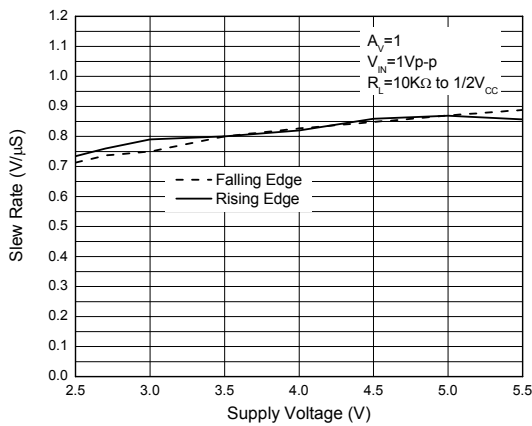


Figure 6. Slew Rate vs. Supply Voltage

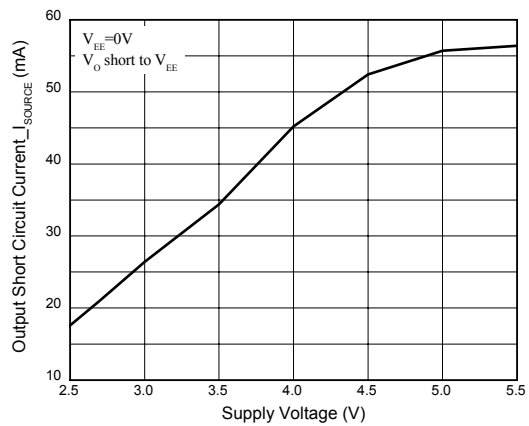


Figure 7. Output Short Circuit Current vs. Supply Voltage



Typical Performance Characteristics (Continued)

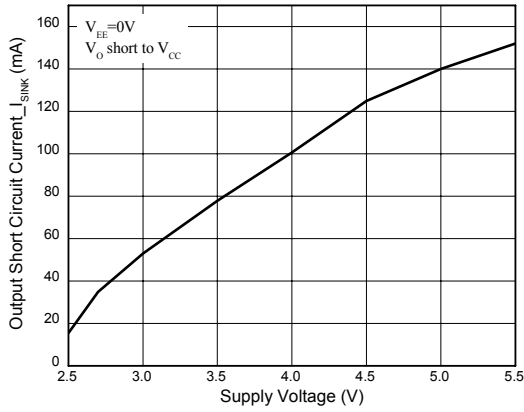


Figure 8. Output Short Circuit Current vs. Supply Voltage

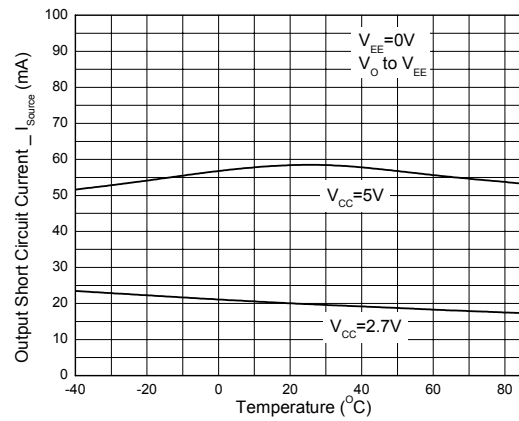


Figure 9. Output Short Circuit Current vs. Temperature

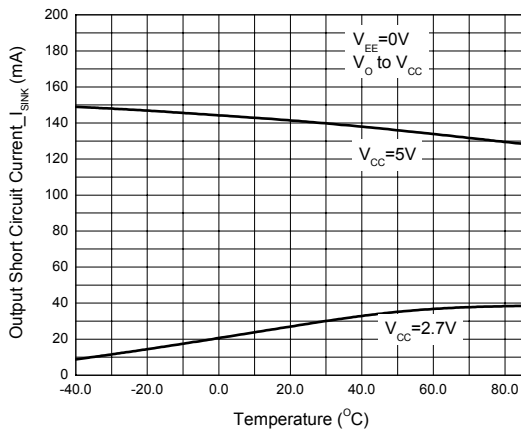


Figure 10. Output Short Circuit Current vs. Temperature

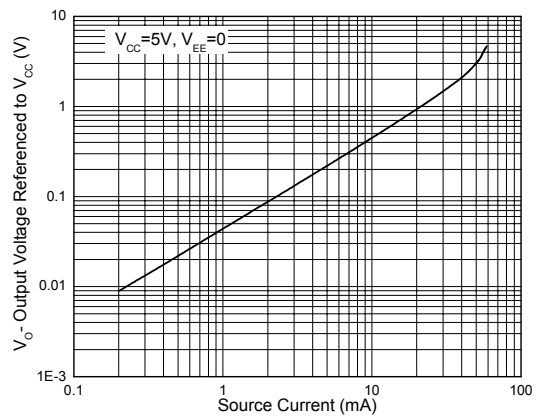


Figure 11. Output Voltage vs. Output Source Current



Typical Performance Characteristics (Continued)

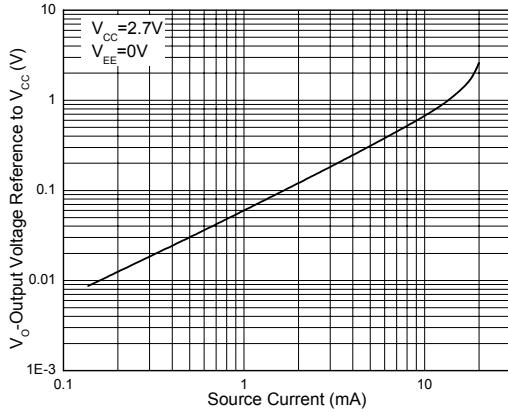


Figure 12. Output Voltage vs. Output Source Current

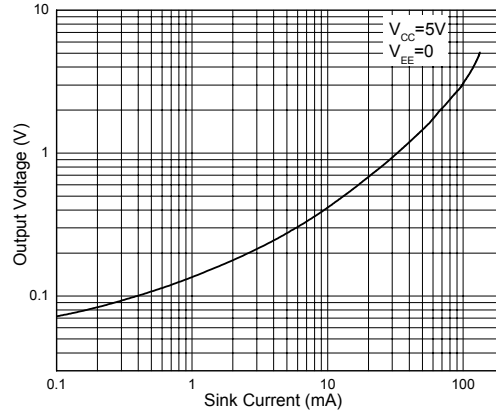


Figure 13. Output Voltage vs. Output Sink Current

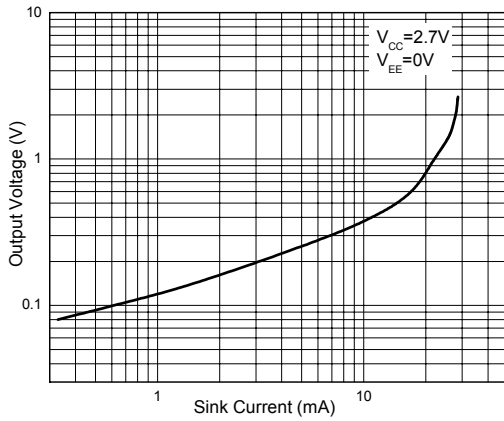


Figure 14. Output Voltage vs. Output Sink Current

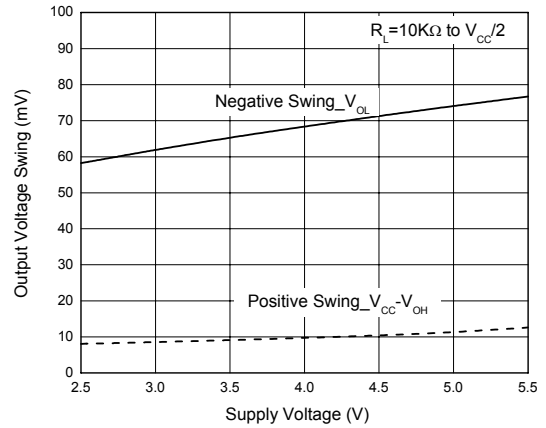


Figure 15. Output Voltage Swing vs. Supply Voltage





Typical Performance Characteristics (Continued)

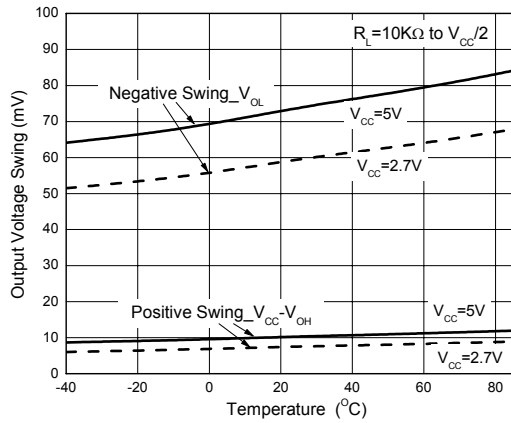


Figure 16. Output Voltage Swing vs. Temperature

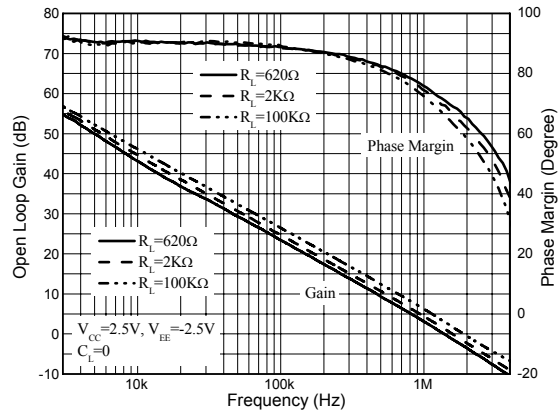


Figure 17. Gain and Phase vs. Frequency and Resistive Load

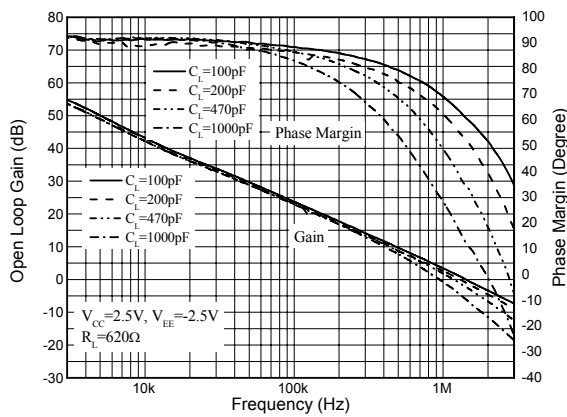


Figure 18. Gain and Phase vs. Frequency and Capacitive Load

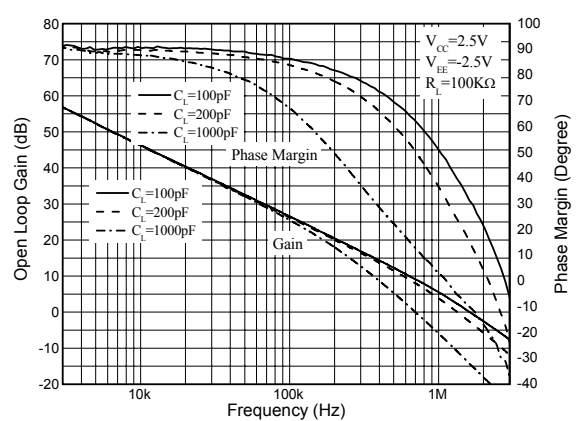


Figure 19. Gain and Phase vs. Frequency and Capacitive Load



Typical Performance Characteristics (Continued)

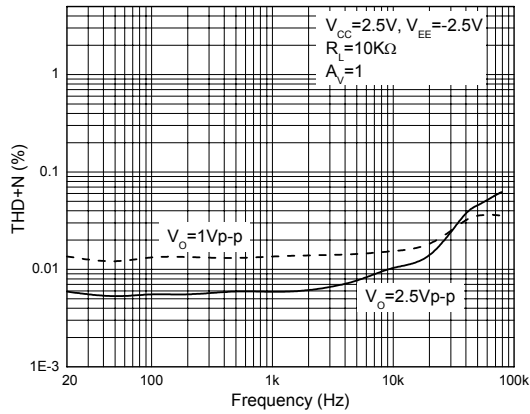


Figure 20. THD+N vs. Frequency

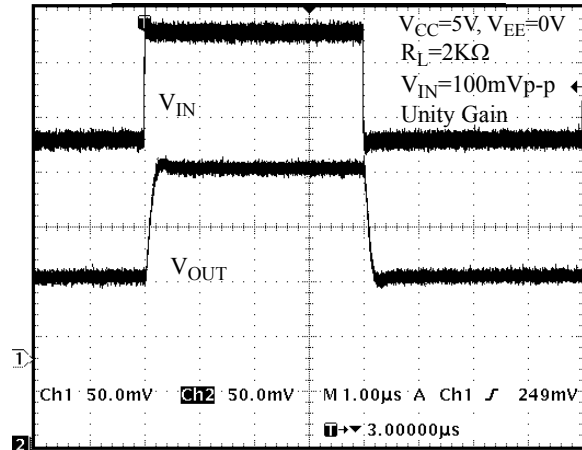


Figure 21. Non-Inverting Input Small Signal Pulse Response

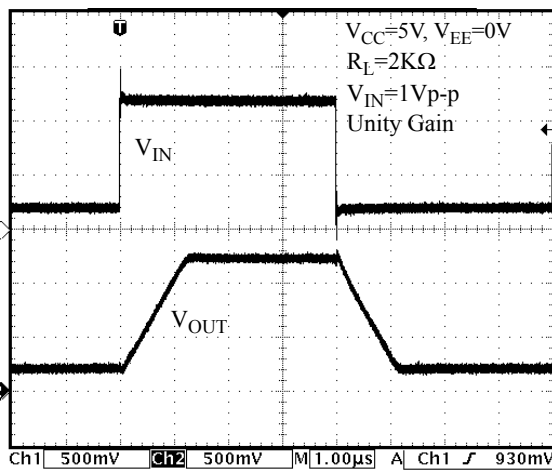


Figure 22. Non-Inverting Input Large Signal Pulse Response

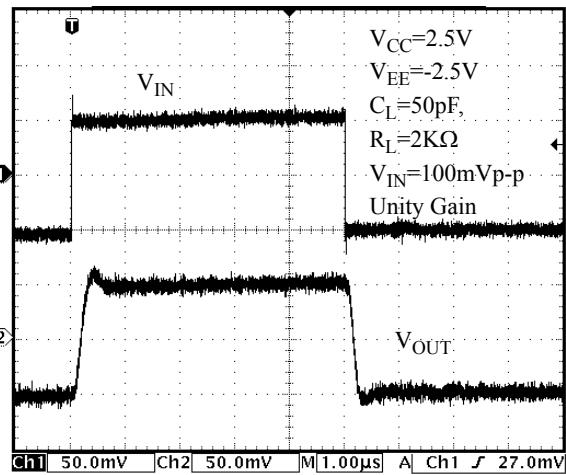


Figure 23. Non-Inverting Input Small Signal Response

**Typical Performance Characteristics (Continued)**

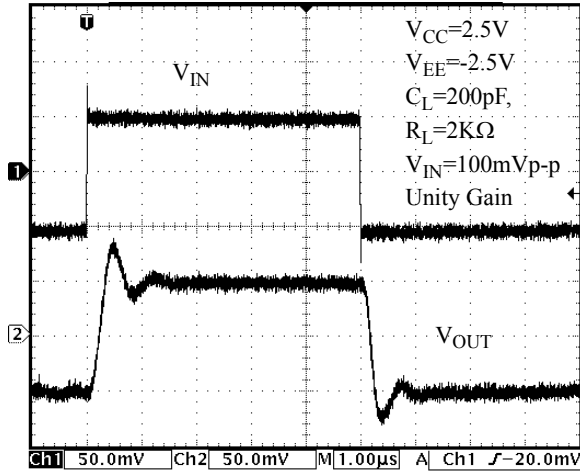


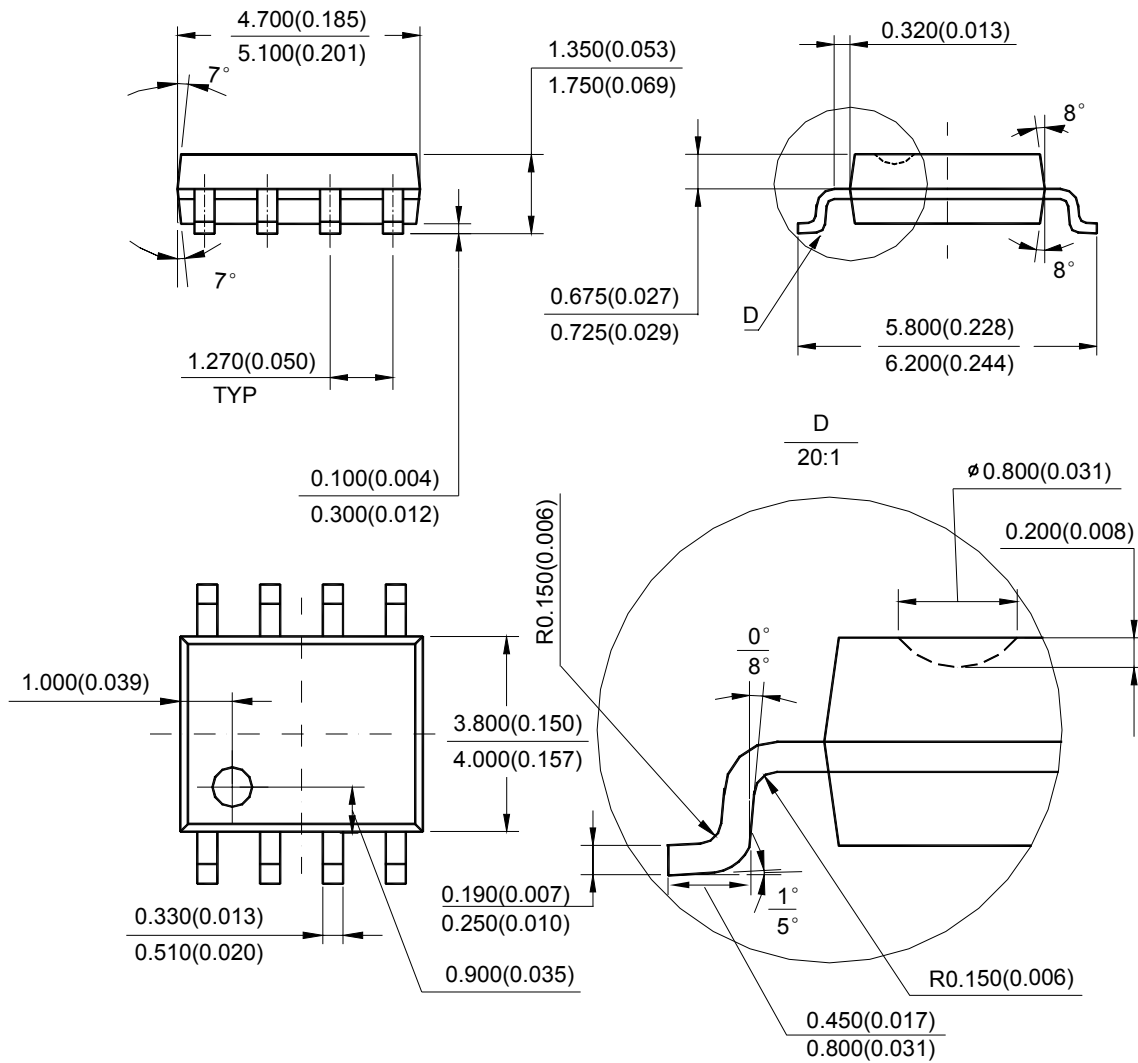
Figure 24. Non-Inverting Input Small Signal Response



Mechanical Dimensions

SOIC-8

Unit: mm(inch)



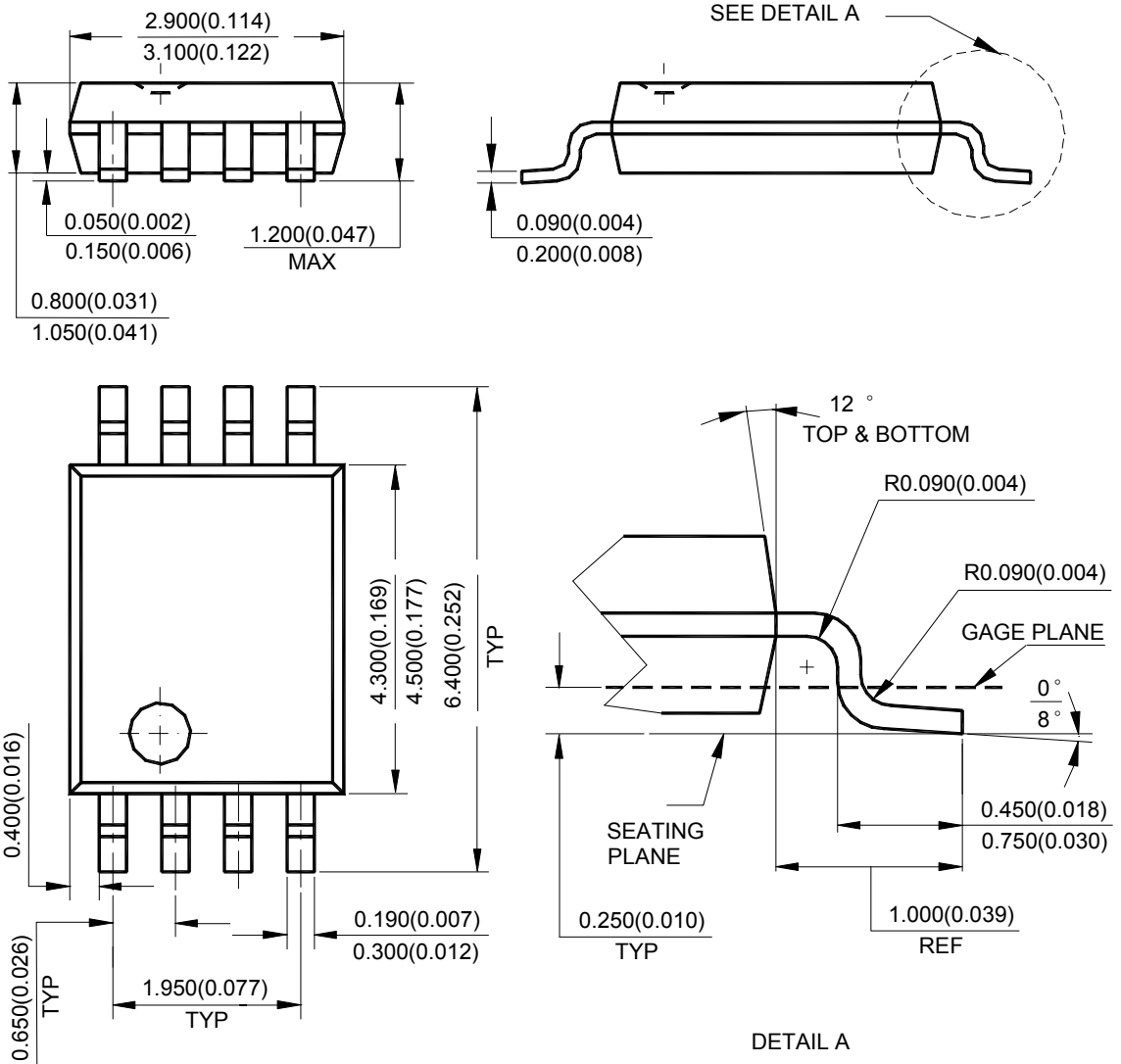
Note: Eject hole, oriented hole and mold mark is optional.



Mechanical Dimensions (Continued)

TSSOP-8

Unit: mm(inch)



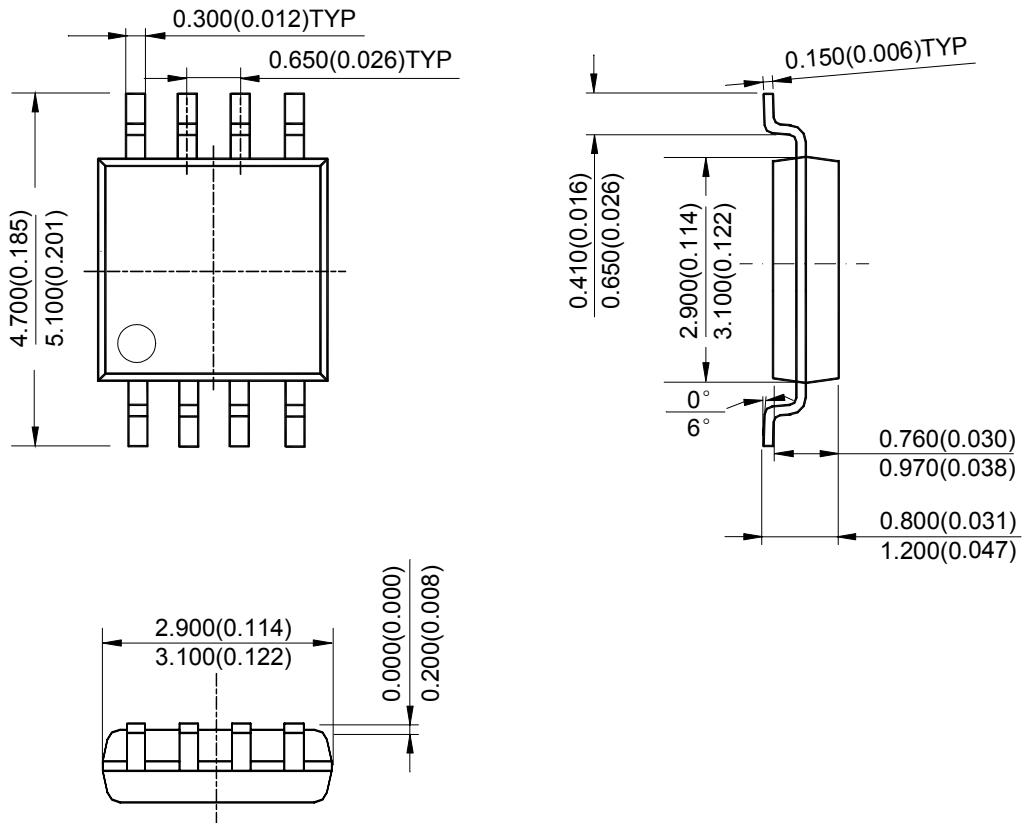
Note: Eject hole, oriented hole and mold mark is optional.



Mechanical Dimensions (Continued)

MSOP-8

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.



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- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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